MB1S-MB8S

Bridge Rectifiers, 0.5 A

Description

The MB family of bridge rectifiers is a 0.5 A rectifier family that achieves high surge current absorption within a very small foot print. Within its small 35 mm² form factor, the MB family shines in its surge capability. In order to absorb high surge currents, the design supports a 35 A I_{FSM} rating and a 5.0 A²Sec I^2T rating. Devices in the family are also rated to breakdown voltages of up to 1000 V. These features make the MB family ideal for small power supplies that need a little extra surge capability.

For higher I_{FAV} current ratings, lower profile packaging, or lower V_F values, explore the ON Semiconductor MDB family of bridge rectifiers. For improved V_F and efficiency values in the MB package or even higher surge capability, ask about ON Semiconductor's pending MBxSV family.

Features

- Low-Leakage
- Surge Overload Rating: 35 A peak
- Ideal for Printed Circuit Board
- UL Certified: UL #E258596
- NRV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- This Device is Pb-Free and RoHS Compliant



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SOIC4 W CASE 751EP

MARKING DIAGRAM



\$Y = ON Semiconductor Logo &Z = Assembly Plant Code

&3 = 3-Digit Data Code (Year & Week)

MB*S = Specific Device Code

* = 1/2/4/6/8

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

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ABSOLUTE MAXIMUM RATINGS

(Values are at $T_A = 25^{\circ}C$ unless otherwise noted)

Symbol	Parameter	MB1S	MB2S	MB4S	MB6S	MB8S	Unit
V_{RRM}	Maximum Repetitive Reverse Voltage 100 200 400 600 80		800	٧			
V _{RMS}	Maximum RMS Bridge Input Voltage 70 140 280		420	560	V		
V_{R}	DC Reverse Voltage (Rated V _R)		200	400	600	800	V
I _{F(AV)}	Average Rectified Forward Current at T _A = 50°C		0.5		Α		
I _{FSM}	Non-Repetitive Peak Forward Surge Current: 8.3 ms Single Half-Sine-Wave		35		Α		
T _{STG}	Storage Temperature Range		-55 to +150		°C		
TJ	Operating Junction Temperature Range		-55 to +150		°C		

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Symbol	Parameter	Value	Unit
P _D	Power Dissipation	1.4	W
$R_{ heta JA}$	Thermal Resistance, Junction to Ambient, per Leg (Note 1)	85	°C/W
$R_{ heta JL}$	Thermal Resistance, Junction to Lead, per Leg (Note 1)	20	°C/W

^{1.} Device mounted on PCB with 0.5×0.5 inch $(13 \times 13$ mm) lead length.

ELECTRICAL CHARACTERISTICS (Values are at T_A = 25°C unless otherwise noted)

Symbol	Parameter	Conditions	Value	Unit
V _F	Forward Voltage, per Bridge	I _F = 0.5 A	1.0	V
I _R	Reverse Current, per Leg at Rated V _R	T _A = 25°C	5.0	μΑ
		T _A = 125°C	0.5	mA
I ² t	I ² t Rating for Fusing	t < 8.3 ms	5.0	A ² s
C _T	Total Capacitance, per Leg	V _R = 4.0 V, f = 1.0 MHz	13	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

ORDERING INFORMATION

Part Number	Top Mark	Package	Shipping [†]	
MB1S, NRVMB1S*	MB1S	SOIC4 W (Pb-Free)	3,000 / Tape & Reel	
MB2S, NRVMB2S*	MB2S	(PD-Free)		
MB4S, NRVMB4S*	MB4S			
MB6S, NRVMB6S*	MB6S			
MB8S, NRVMB8S*	MB8S			

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}NRV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable

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TYPICAL PERFORMANCE CHARACTERISTICS

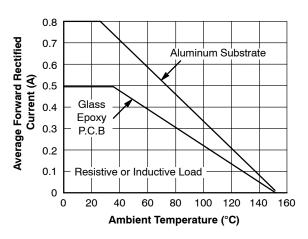


Figure 1. Derating Curve for Output Rectified Current

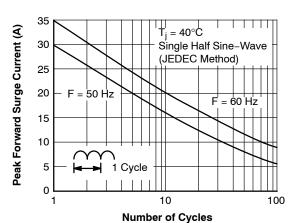


Figure 3. Maximum Non-Repetitive Peak Forward Surge Current Per Leg

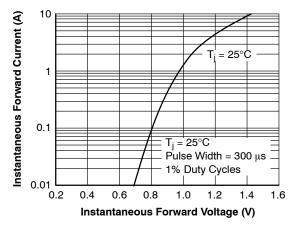


Figure 5. Typical Forward Voltage Characteristics
Per Leg

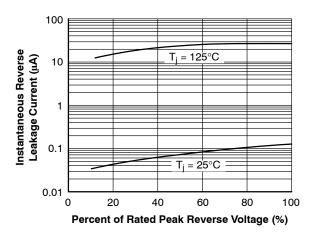


Figure 2. Typical Reverse Leakage Characteristics
Per Leg

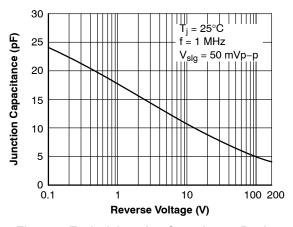
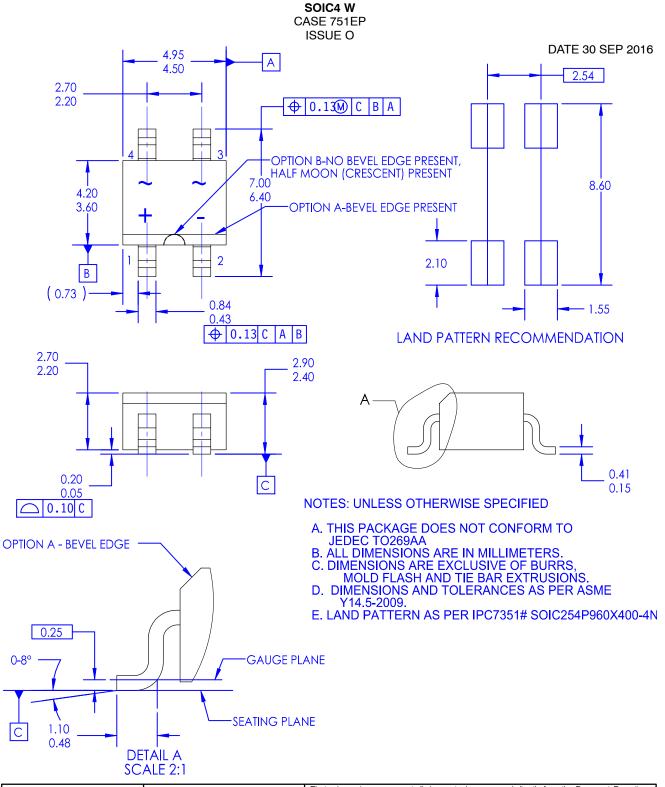


Figure 4. Typical Junction Capacitance Per Leg



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